NSN 5962-01-076-8398

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Body Length:	
0.440 inches	
Body Width:	
Between 0.248 ir	ches and 0.325 inches
Body Height:	
0.085 inches	
Maximum Powe	r Dissipation Rating:
910.0 milliwatts	
Operating Temp	urature Range:
·55.0/+125.0 deg	rees celsius
Storage Tempu	ature Range:
-65.0/+150.0 deg	rees celsius
Features Provid	ed:
Hermetically sea	ed and monolithic and positive outputs and w/storage and programmable and programmed and bipolar and 3-state output
and schottky and	high speed and expandable and w/buffered output and w/decoded output and w/enable and w/disable
nclosure Mater	al:
Ceramic and glas	S
Inclosure Config	guration:
Flat pack	
Output Logic Fo	rm:
Transistor-transis	tor logic
Input Circuit Pa	tern:
6 input	
Ferminal Surfac	e Treatment:
Solder	
Voltage Rating	And Type Per Characteristic:
5.5 volts powers	source
Time Rating Per	Chacteristic:
40.00 nanosecor	ds propagation delay time, low to high level output and 84.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	Туре:
Rom	
Memory Capaci	y:
Unknown	
Test Data Docu	nent:
82577-932821 st	andard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type A	Ind Quantity:
16 flat leads	
Shelf Life:	
N/a	
Unit Of Measure	:
Demilitarization	

Yes - demil/mli

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